

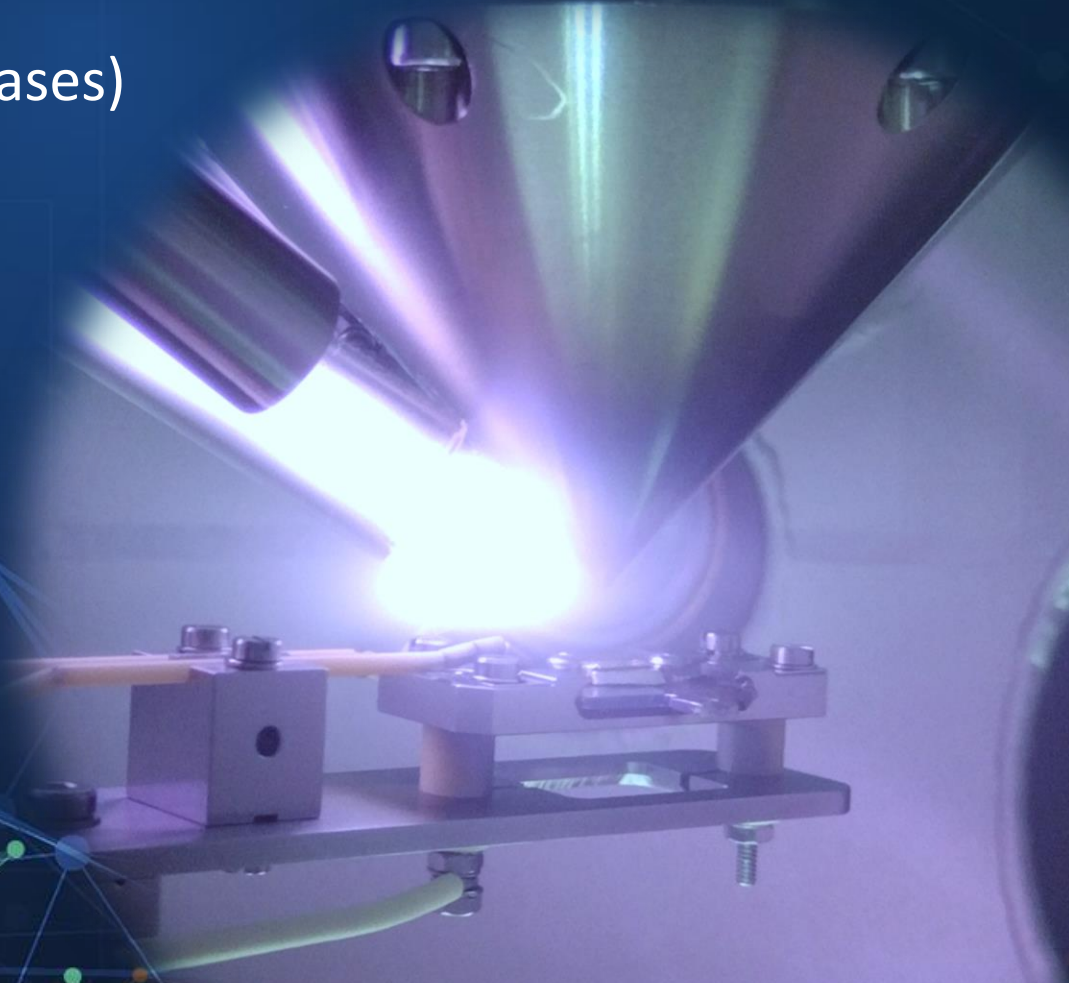
Plasma XPS: a New Operando Metrology for Semiconductor Process Development and Control

Andrei Kolmakov

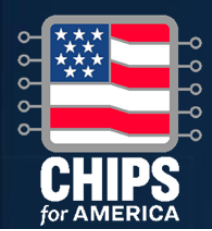
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FCMN, Monterey, CA, March 2026

- XPS of solids (in UHV)
- XPS of gases (and solids in gases)
- XPS in liquids
- **XPS in plasmas**



- Motivation: NIST CHIPS R&D Metrology program and beyond
- Prior efforts and current state
- Experimental
- Application Examples
- Plasma diagnostics
- Summary



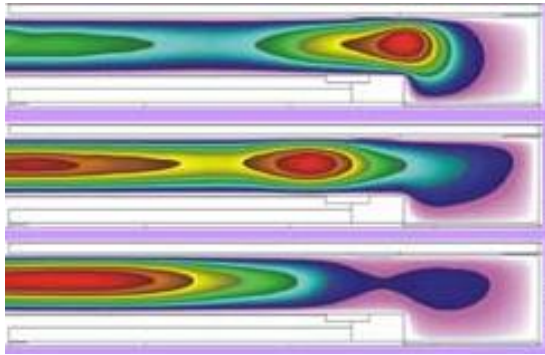
Disclaimer



This work was performed with funding from the CHIPS Metrology Program, part of CHIPS for America, National Institute of Standards and Technology, U.S. Department of Commerce.

- Statements and responses to questions about advanced microelectronics research and development programs in this presentation:
 - Are informational, pre-decisional, and preliminary in nature.
 - Do not constitute a commitment and are not binding on NIST or the Department of Commerce.
 - Are subject in their entirety to any final action by NIST or the Department of Commerce.
- Nothing in this presentation is intended to contradict or supersede the requirements published in any future policy documents or Notices of Funding Opportunity.

The need for *in situ* (nanoscale) characterization of surface/interface morphologies *during* plasma treatments



Plasma-liquid-solid interactions, chemistry and (nano-)materials synthesis

Image credit: M. Kushner. Uni. Michigan

Semiconductor processing

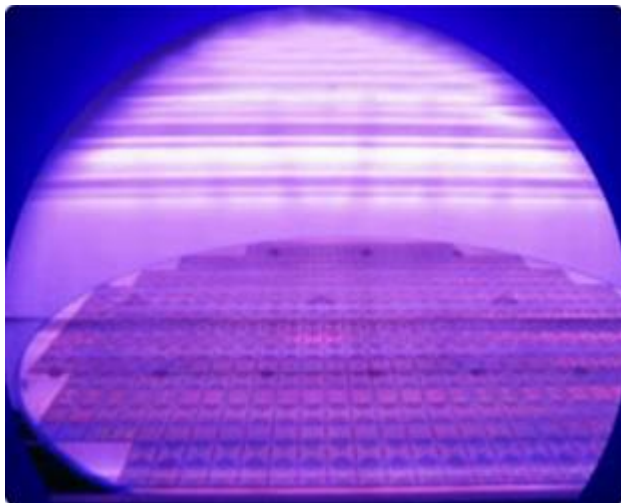


Image: Picotech.com

Biomedical

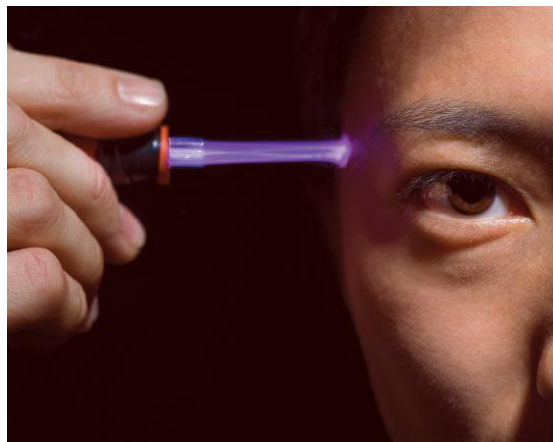


Image credit: Texas A&M University

Plasma catalysis

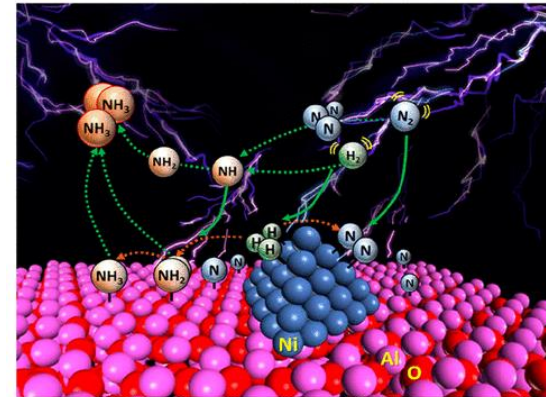
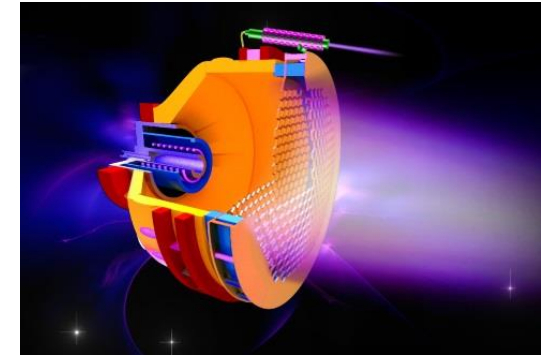


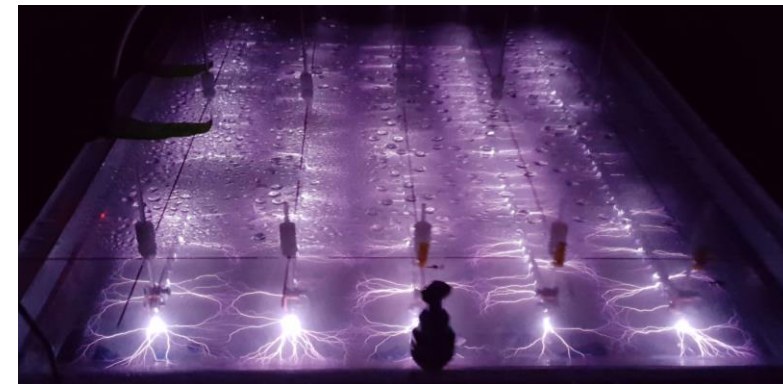
Image credit: Xin Tu, ACS Catalysis

Aerospace



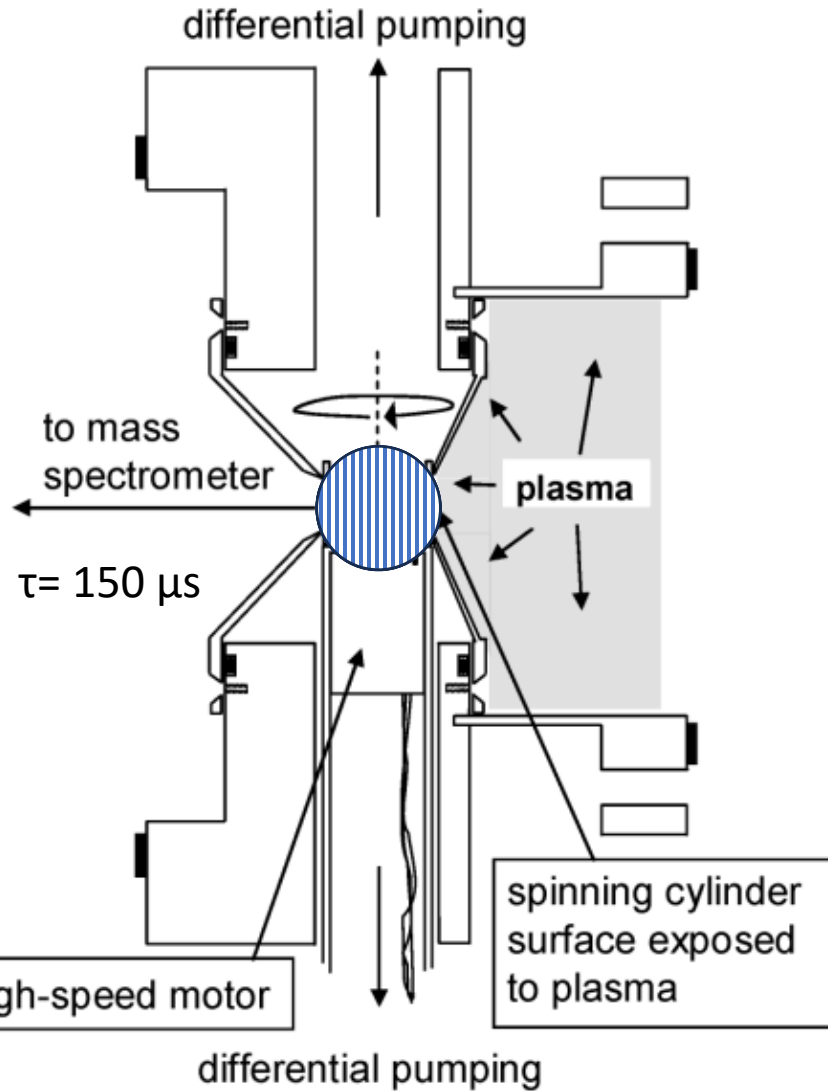
<https://iopscience.iop.org/>

Remediation technologies



Courtesy photo/Clarkson University

Prior efforts: spinning wall approach



200 000 rpm

PRL **96**, 018306 (2006)

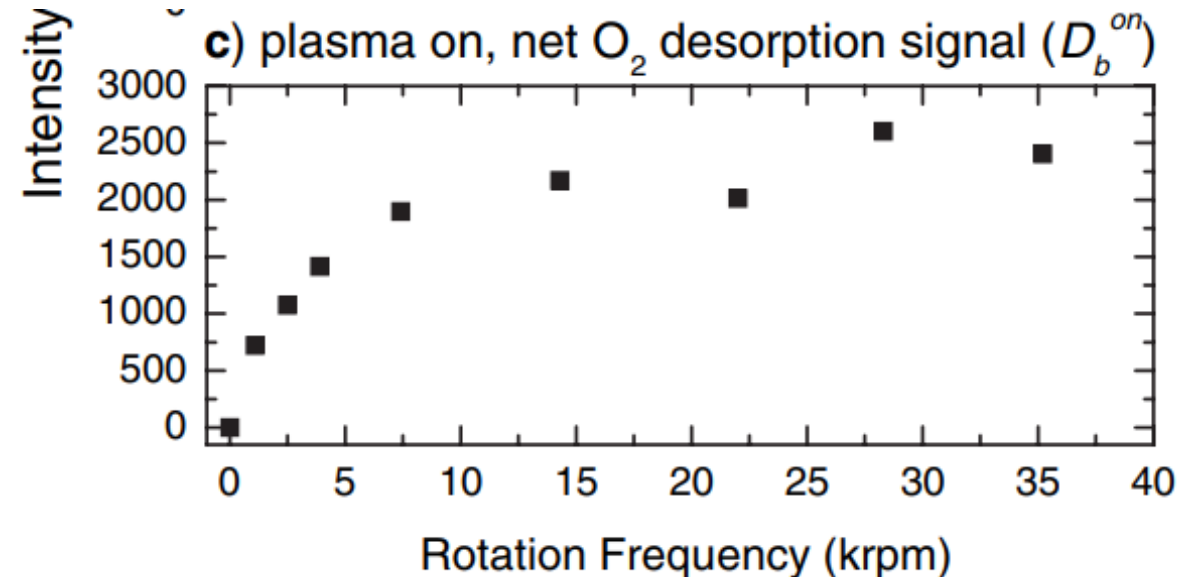
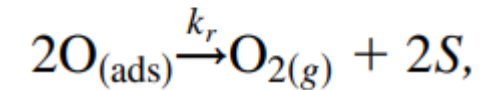
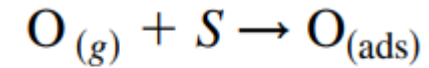
PHYSICAL REVIEW LETTERS

Plasma-Surface Reactions at a Spinning Wall

P. F. Kurunczi, J. Guha, and V. M. Donnelly

Department of Chemical Engineering University of Houston, Houston, Texas 77204, USA

(Received 18 July 2005; published 13 January 2006)



Plasma XPS: current state

NIST

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PHYSICAL
CHEMISTRY
A JOURNAL OF THE AMERICAN CHEMICAL SOCIETY

pubs.acs.org/JPC

Article

Operando XPS for Plasma Process Monitoring: A Case Study on the Hydrogenation of Copper Oxide Confined under h-BN

J. Trey Diulus,^{*} Andrew E. Naclerio, Jorge Anibal Boscoboinik, Ashley R. Head, Evgheni Strelcov, Ivan R. Kidambi, and Andrei Kolmakov^{*}

JVST A
Journal of Vacuum Science & Technology A

LETTER

pubs.aip.org/avs/jva

Operando XPS in reactive plasmas: The importance of the wall reactions

Cite as: J. Vac. Sci. Technol. A 43, 040401 (2025); doi: 10.1116/6.0004569
Submitted: 14 March 2025 · Accepted: 24 April 2025 ·
Published Online: 15 May 2025



J. Trey Diulus,^{1,a)} Ashley R. Head,² Jorge Anibal Boscoboinik,² and Andrei Kolmakov^{1,a)}

JVST A
Journal of Vacuum Science & Technology A

LETTER

pubs.aip.org/avs/jva

Toward the origins of binding energy shifts and “satellites” formation during plasma-XPS measurements

Cite as: J. Vac. Sci. Technol. A 44, 020405 (2026); doi: 10.1116/6.0005249
Submitted: 18 December 2025 · Accepted: 26 January 2026 ·
Published Online: 17 February 2026



J. Trey Diulus,¹ Ashley R. Head,² Jorge Anibal Boscoboinik,² Carles Corbella,³ Alexander Tselev,⁴ and Andrei Kolmakov¹

LANGMUIR

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pubs.acs.org/Langmuir

Article

In Situ Ambient Pressure Photoelectron Spectroscopy Study of the Plasma–Surface Interaction on Metal Foils

Sam Taylor,^{*} Filip Hallböök, Robert H. Temperton, Jinguo Sun, Lisa Rämisch, Sabrina Maria Gericke, Andreas Ehn, Johan Zetterberg, and Sara Blomberg^{*}

Cite This: Langmuir 2024, 40, 13950–13956

Read Online

Review of
Scientific Instruments

ARTICLE

pubs.aip.org/aip/rsi

Extending ambient pressure x-ray photoelectron spectroscopy to plasma studies: A custom-built plasma source apparatus

Cite as: Rev. Sci. Instrum. 96, 065203 (2025); doi: 10.1063/5.0249456
Submitted: 18 November 2024 · Accepted: 13 May 2025 ·
Published Online: 5 June 2025



Yang Gu,^{1,2} Zhenhao Qiu,¹ Shui Lin,^{1,2} Yong Han,² Hui Zhang,³ Zhi Lin,^{1,2,a)} and Jun Cai^{1,2,a)}

SSS
SURFACE SCIENCE SPECTRA

ARTICLE

pubs.aip.org/avs/sss

In situ NAP-XPS study of plasma-enhanced silver oxidation and reduction reactions

Cite as: Surf. Sci. Spectra 32, 014005 (2025); doi: 10.1116/6.0004223
Submitted: 22 November 2024 · Accepted: 12 March 2025 ·
Published Online: 27 March 2025



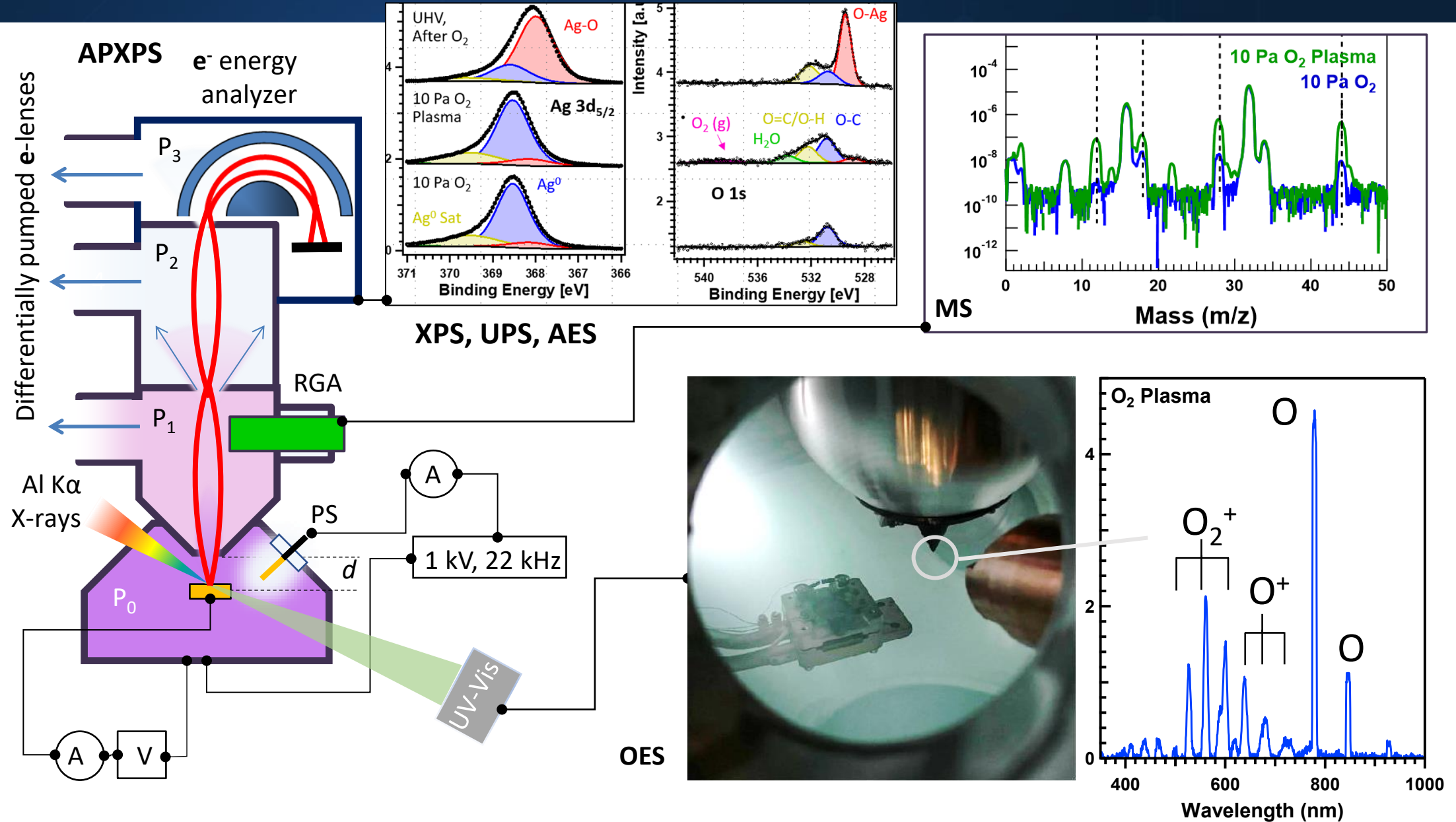
Paul M. Dietrich^{a)} and Andreas Thissen

Experimental setup

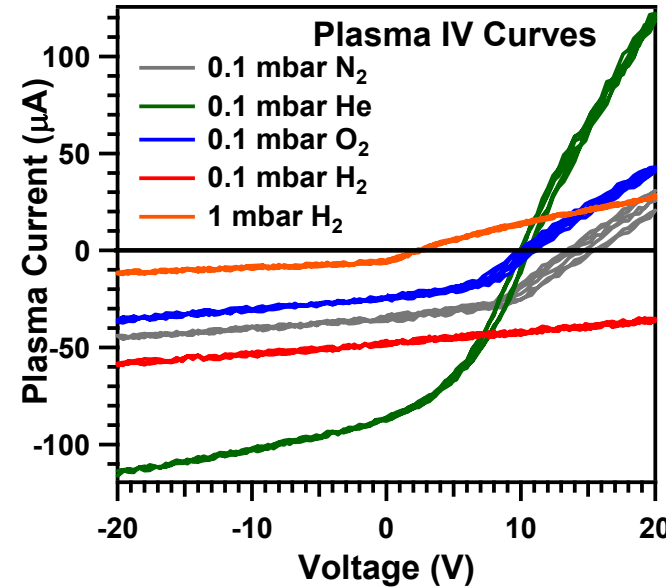
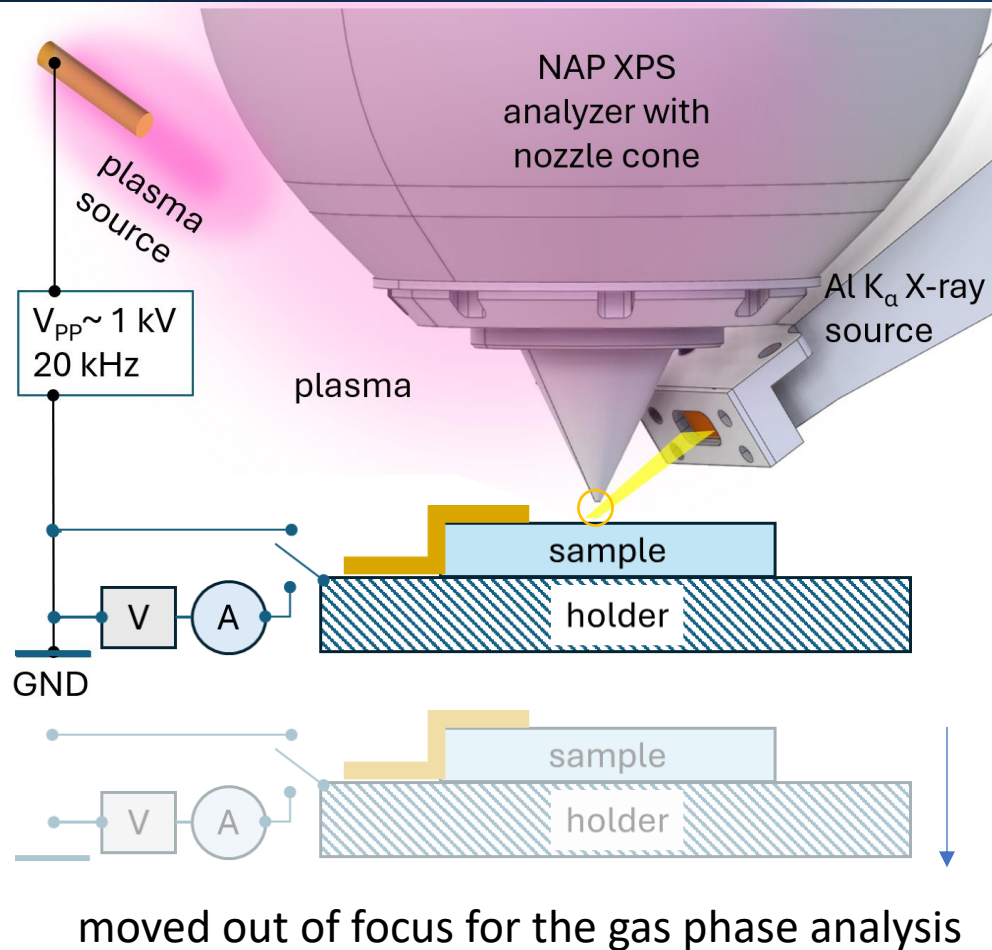


BNL/CNF

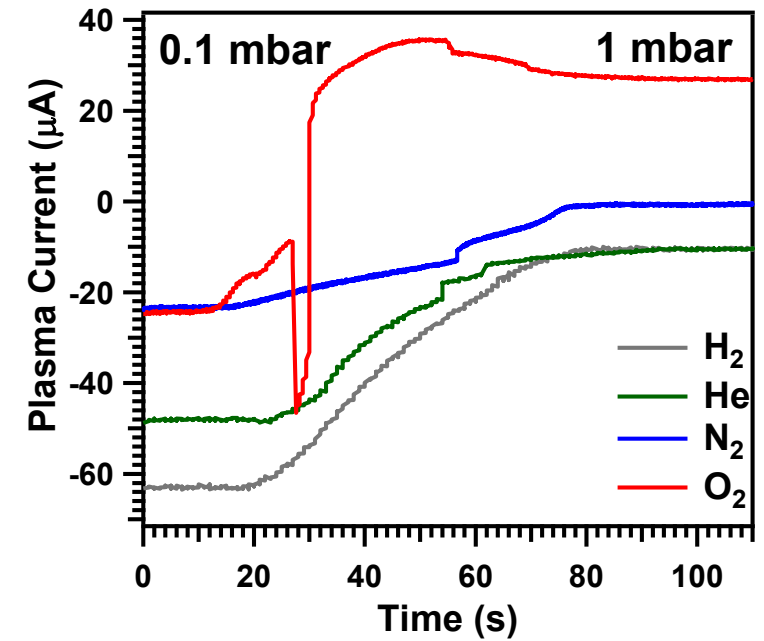
NIST



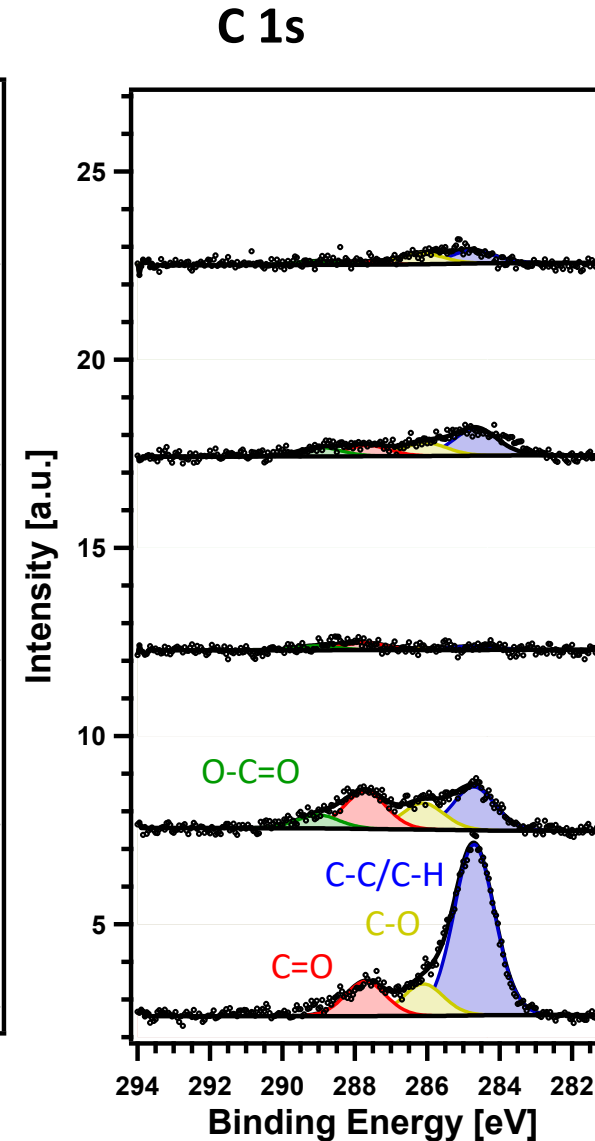
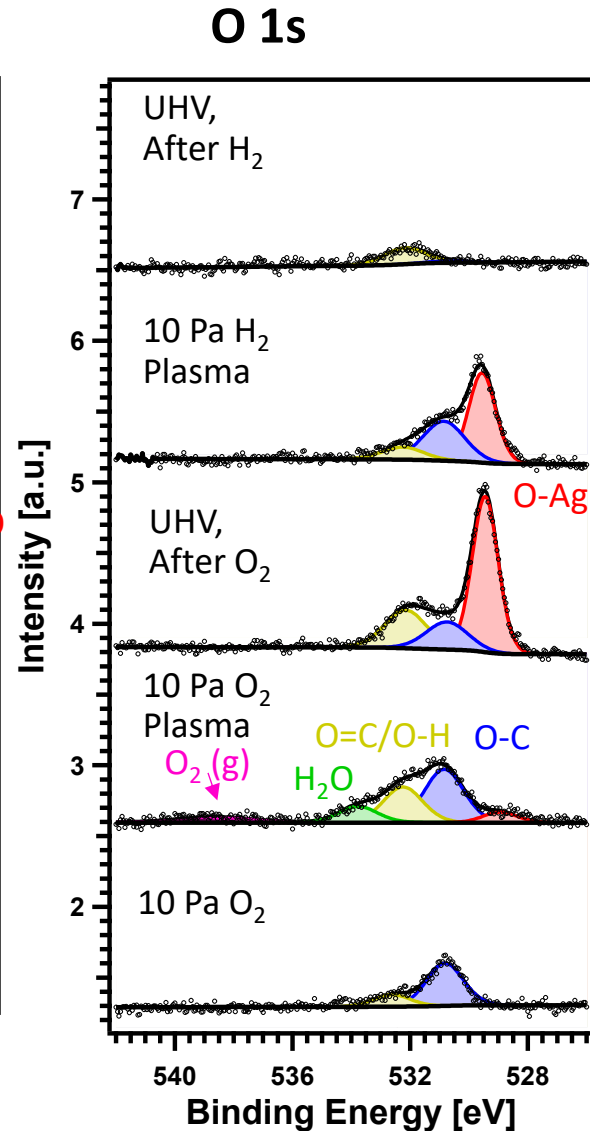
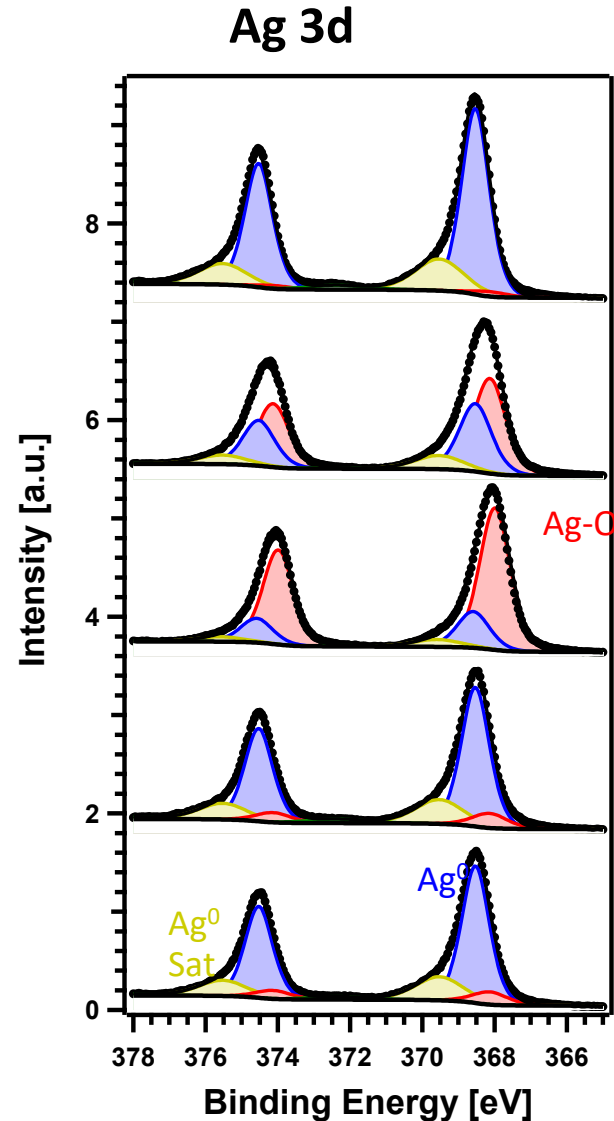
Experimental setup



Complementary Langmuir probe-like electrical measurements for plasma characterization



Application Example: Cleaning/Oxidation/Reduction/Wall reactions



AgO_x is reduced by H₂ plasma

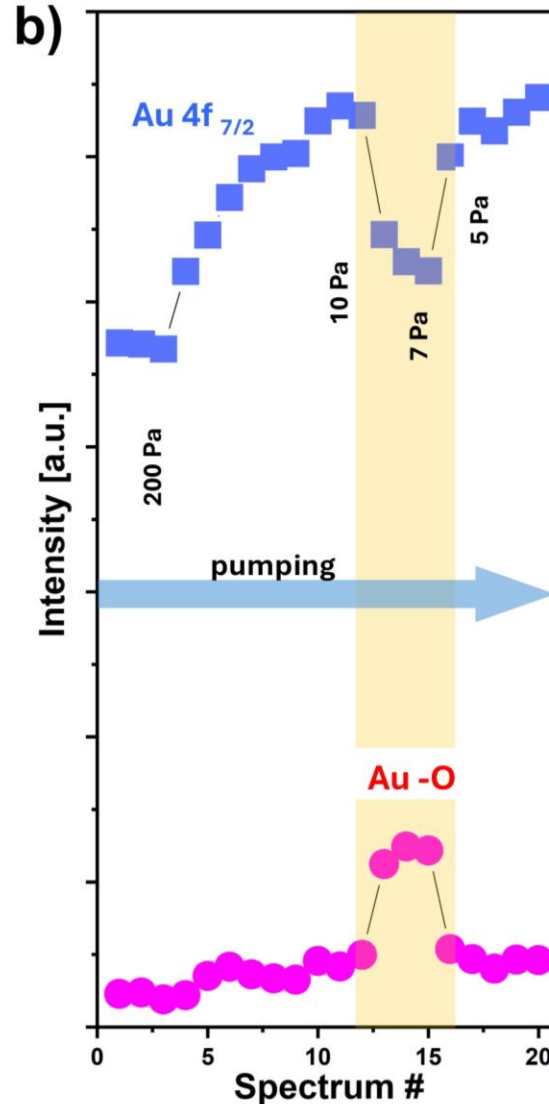
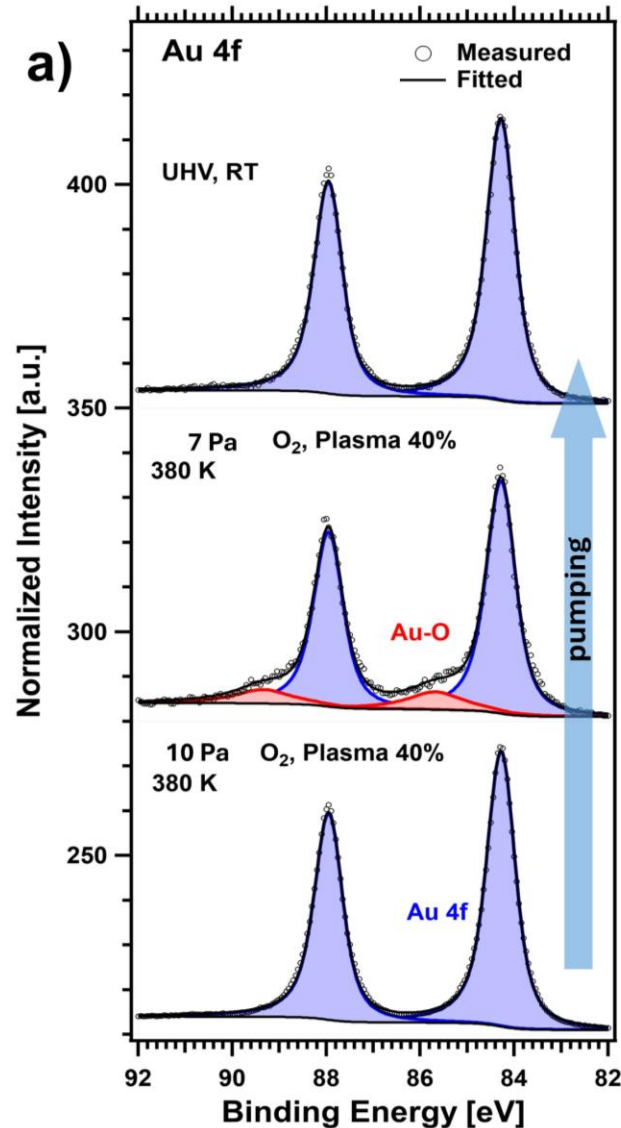
H₂ plasma induces some contamination again due to the parasitic plasma-induced wall reactions

C-contaminations are completely removed by O₂ plasma

O₂ plasma cleans and then oxidizes Ag to AgO_x

Initial contaminated and partially oxidized Ag.

Application Example: Detection of unstable “states”



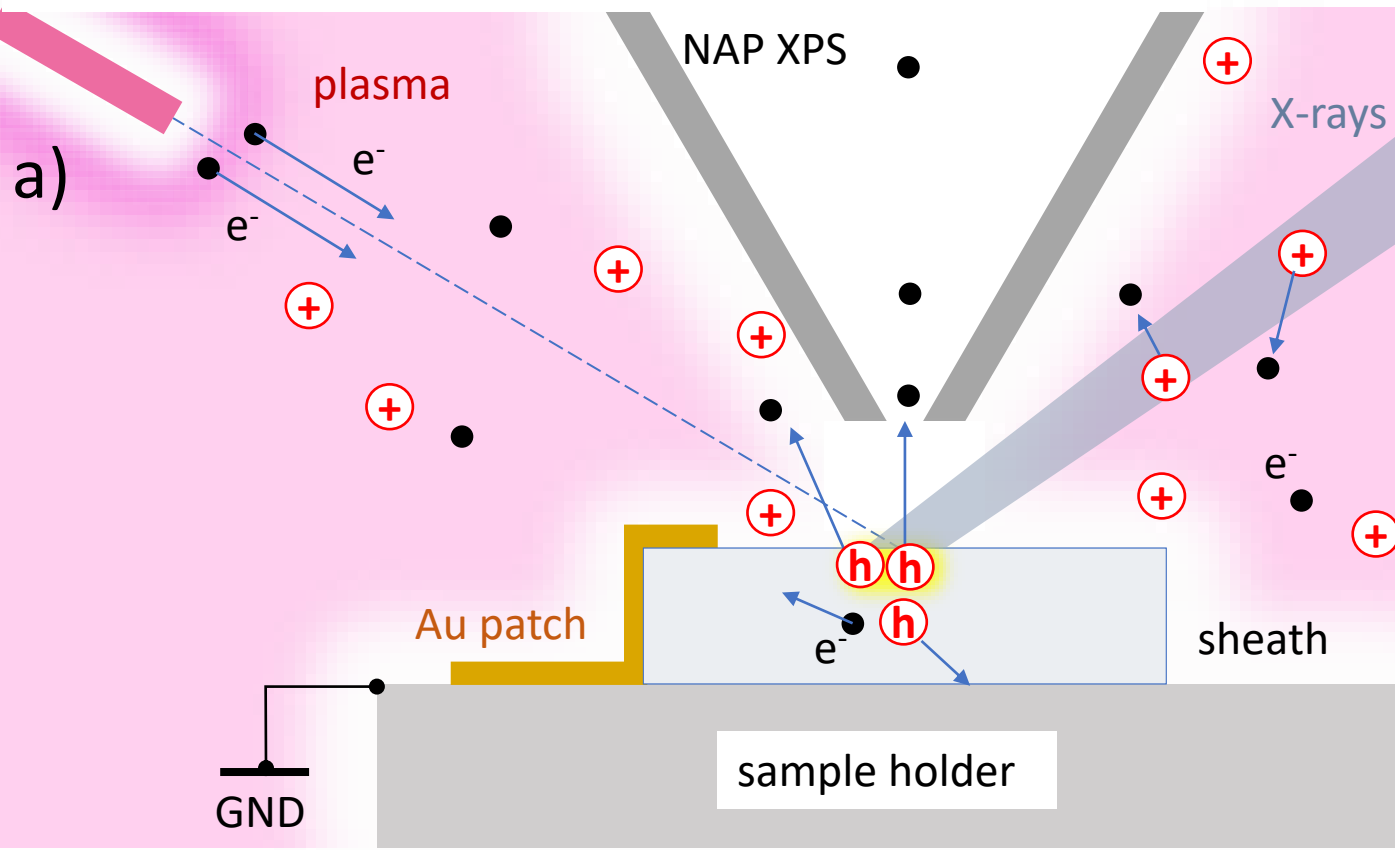
Au oxide is **unstable** in UHV and at elevated temperatures

The dynamic equilibrium between incoming oxygen radicals reacting with Au and the desorption of O₂ results in the metastable Au-oxide that can be detected at the surface by Plasma-XPS.

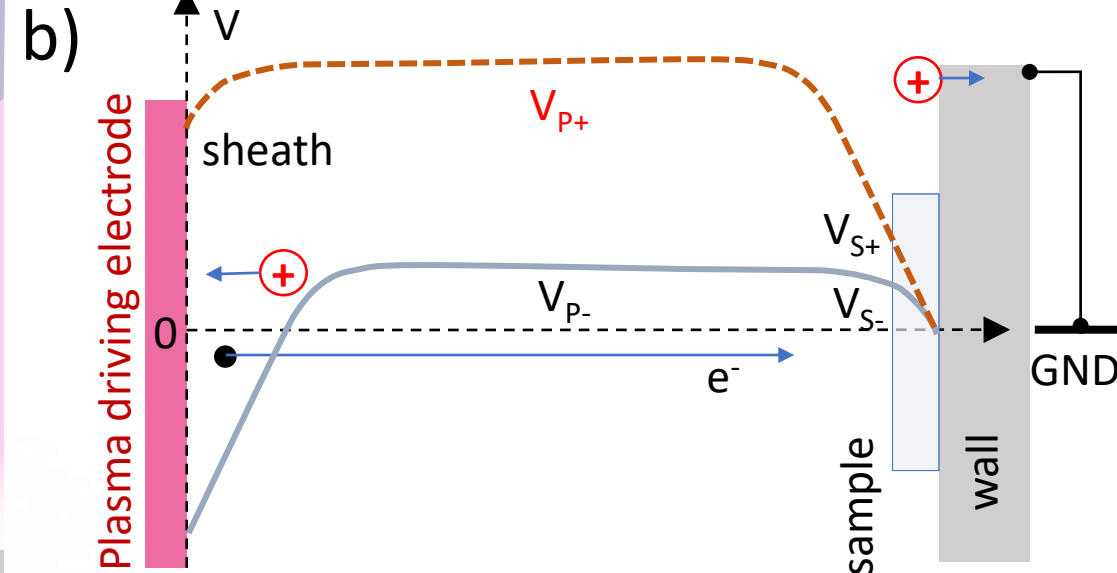
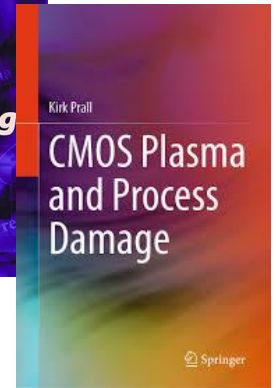
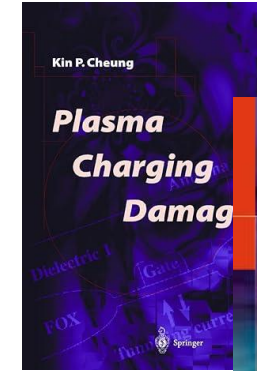
Plasma potentials & sample charging

Surface charge depends on:

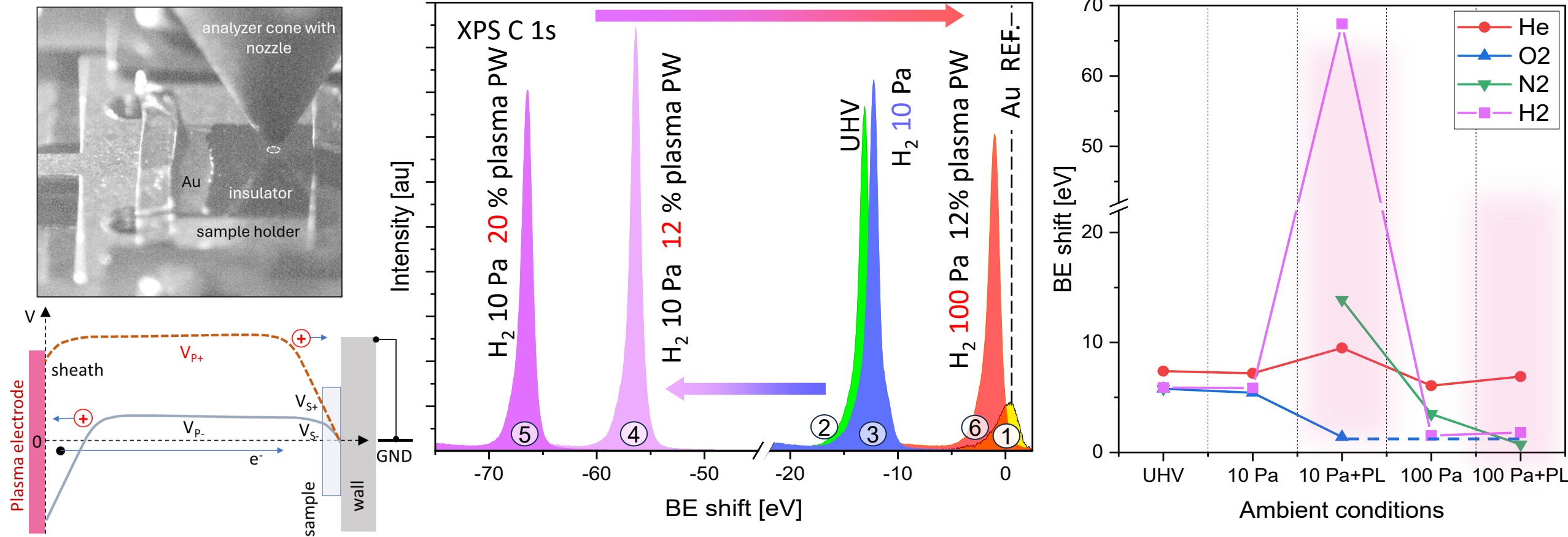
- Electrons/ions, secondary electrons, photoelectrons
- UV-Vis photons
- EM field
- Reactive radicals
- Surface temperature



Importance:



Application Example: Diagnostics of the sample charge



UV light 

Cycle-averaged plasma potential 

Ballistic electrons from the cathode at the cathode cycle 

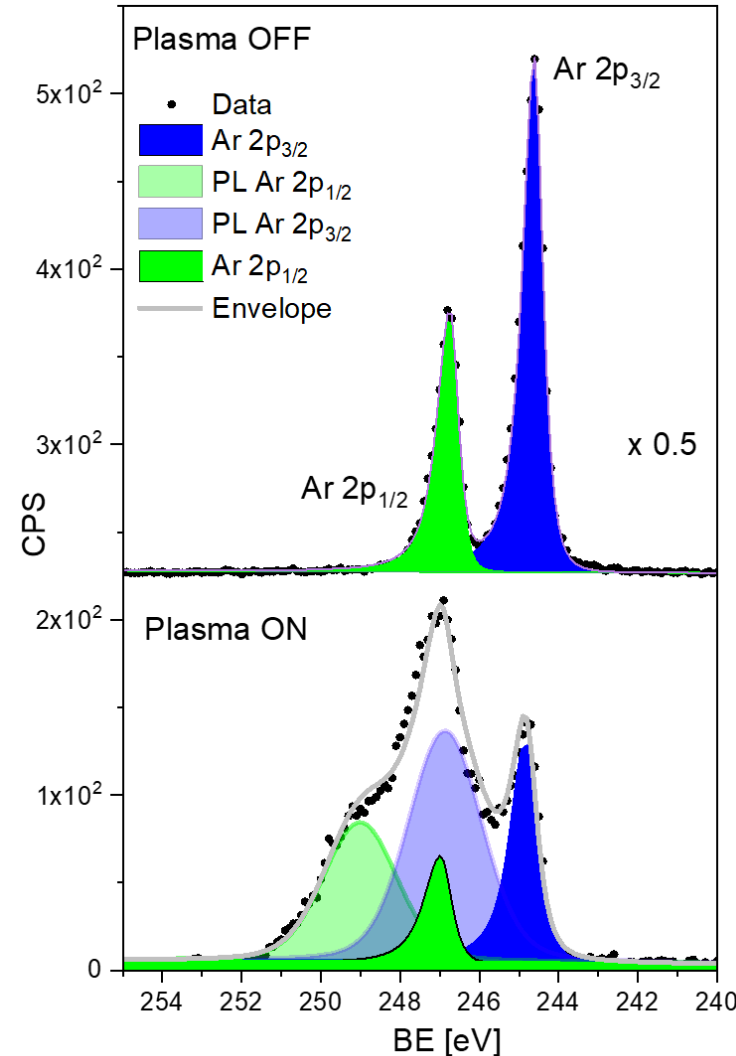
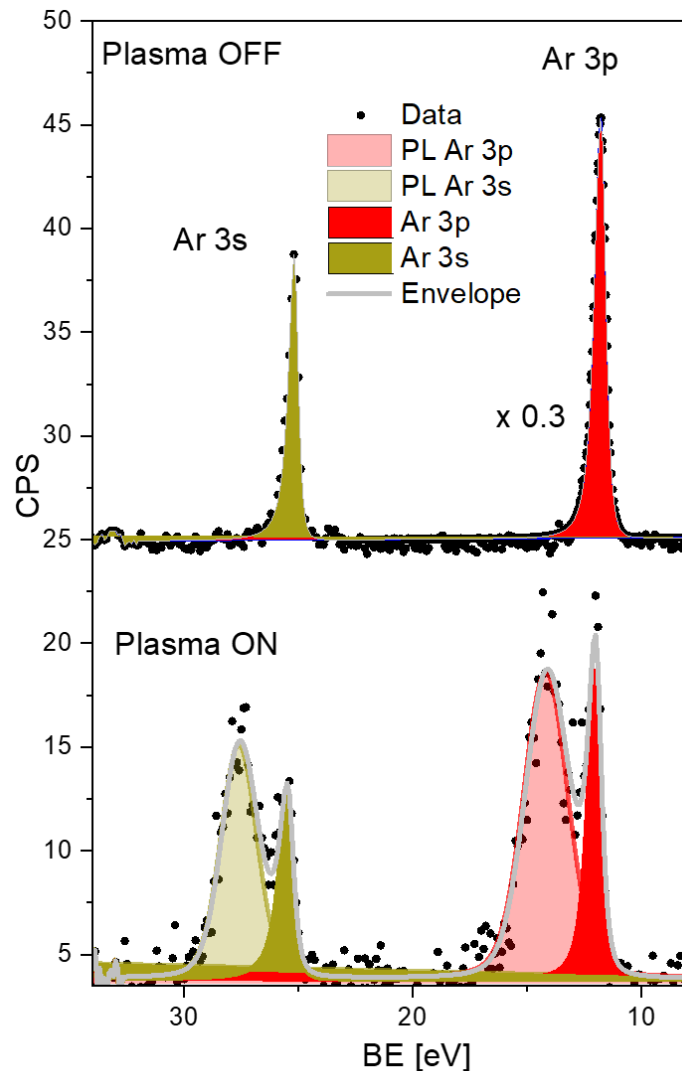
Reduced recapture of the photoemitted electrons at low pressure 

At high pressure, the increased electron scattering and near-surface gas ionization, results in charge neutralization.

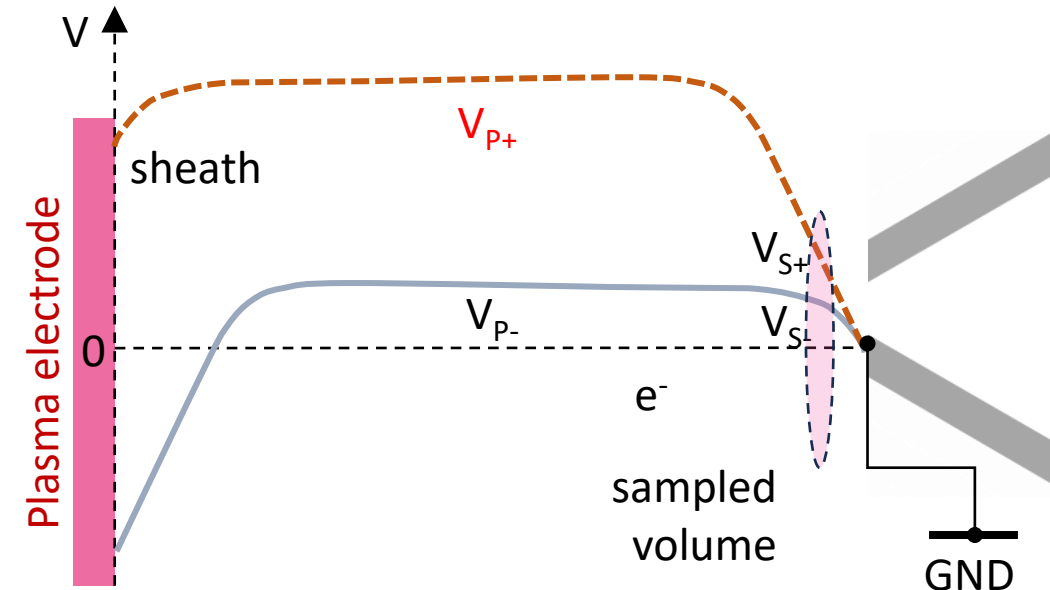
In electronegative plasma-electrons are effectively captured

Plasma diagnostics: Gas phase XPS & plasma potential

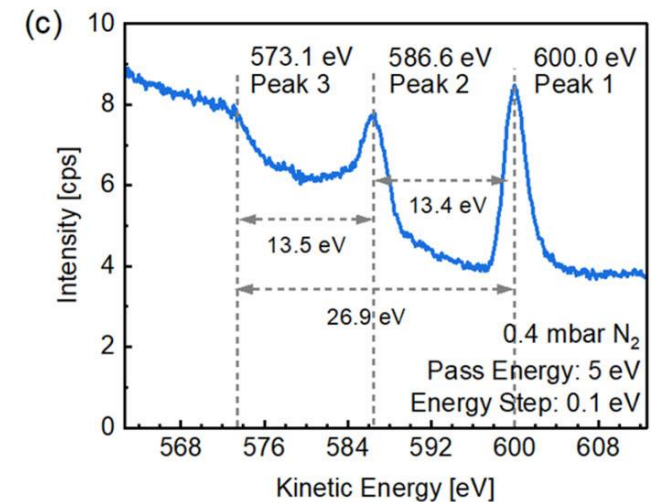
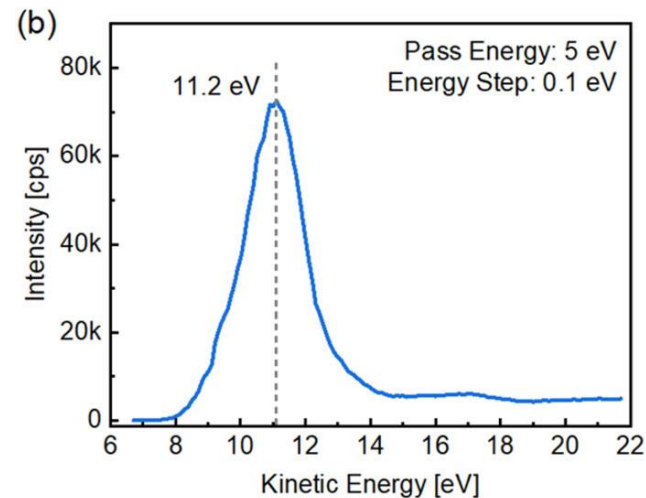
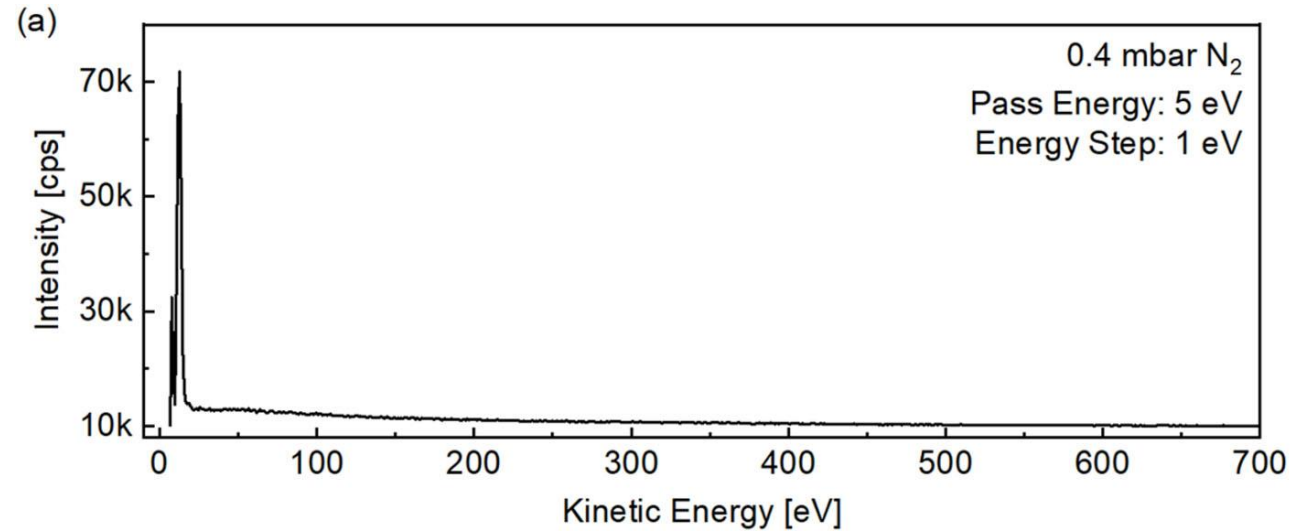
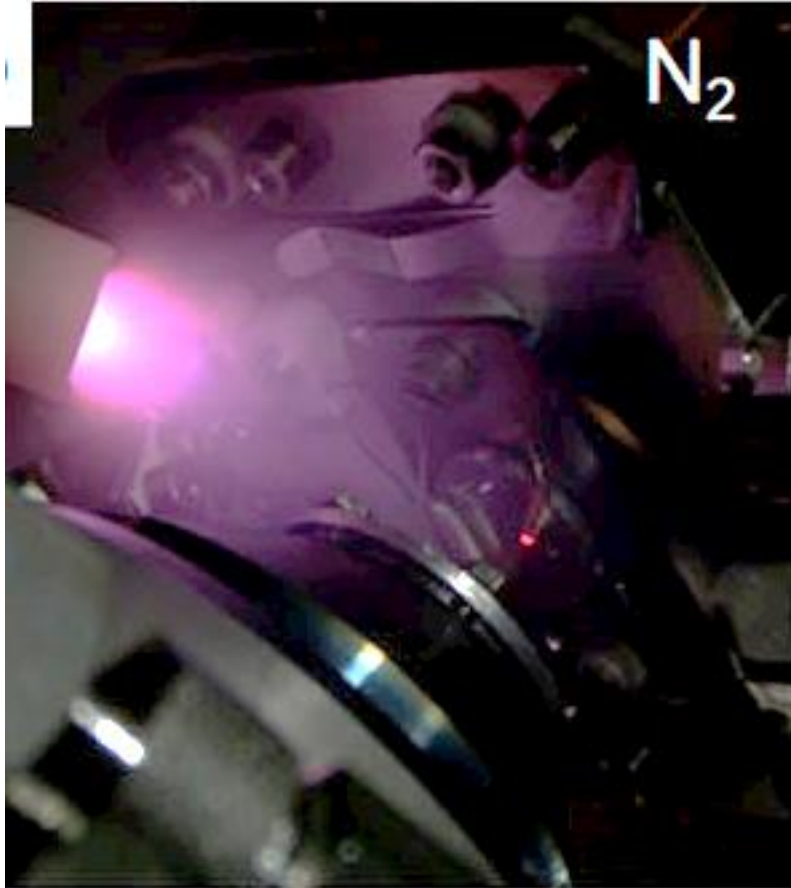
Ar 500 Pa, Plasma: AC 22 kHz , 1 kV pk-pk



- Appreciable reduction of the intensity of the main peaks while the integrated area stays the same
- Slight shift of the main peaks position toward the higher BE
- Slight broadening of the main peaks and
- The most pronounced effect is the appearance of prominent, broad satellite peaks at higher binding energies ($\Delta \sim 2\text{eV}$)



Plasma Diagnostics: Electron Energy Distribution ?



- Plasma-XPS metrology-the unique capability to detect **real-time chemical state** (e.g., due to short-living transients) not accessible in conventional “before & after” XPS
- **XPS peaks shifts**, and broadening can be used for **plasma-induced surface charge** analysis
- **Gas phase Plasma XPS** can be used as a **plasma diagnostic tool**: chemical composition, plasma potential, electron energy distribution (to be proved), and ion energy distribution (to be tested)

Acknowledgments



Dr. Trey Diulus

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Boscoboinik, BNL

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